



Upgrade your SEM with a retractable BSE detector.

REBEKA™ combines the best available single crystal scintillators manufactured by Crytur with precise high-vacuum mechanics and readout electronics in one ready-to-use package.

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SPI Supplies Division of STRUCTURE PROBE, Inc.

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REBEKA BSE Detector for SEM



The Rebeka Backscatter detector is a scintillator based detection unit for scattered electrons which includes YAG:Ce scintillator and light-guide (Sensor Unit), vacuum optical feed-through, bellows based vacuum retraction mechanism (Mechanical Unit), photomultiplier (PMT) and Electronics Control Unit. The scintillator is a YAG:Ce single crystal with a conductive ITO coating. The scintillating light is detected by the PMT module. The retractable vacuum mechanics is motorized. The REBEKA can be fitted to most SEMs.

System Features

Sensor Unit:

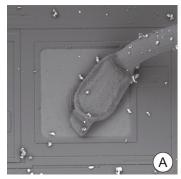
- YAG:Ce (CRY 18) scintillator with optimized efficiency and minimized afterglow.
- Exclusive CRYTUR LOW-ENERGY COATING™ sensitive down to 0.2 keV
- Exponential decay time: 45 ns with 30 photons/keV
- Outer diameter: 15 mm
- Inner hole diameter: 3/2/1.5 or 1 mm
- Sensitivity: down to 1pA beam current

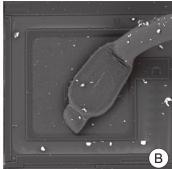
Mechanical Unit:

- Dimensions: 406 x 100 x 72 mm
- Bellows design for ultimate vacuum
- 150 mm motorized retraction
- +/- 2 mm fine adjustment in x, y, z axis
- 0.01 mm repeatability
- Flange adapted to customer's SEM system

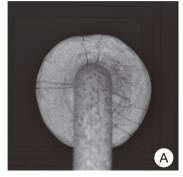
Electronics Control Package:

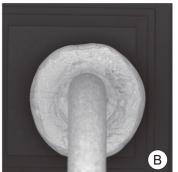
- Dimensions 210 x 180 x 80 mm
- Supply 230/110 V
- 3 noise filters optimized for different scanning speeds
- 50 MHz bandwidth
- Internal source 0-1200 V for PMT HV
- Output video signal -1/+1V (-5/+5V)
- Full remote software control





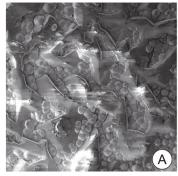
Sample: IC bonds - Al bond on Si wafer with partial contamination. **A** BSE 3kV | 80pA | 320 µs/pxl **B** BSE 3kV | 10pA | 100 µs/pxl

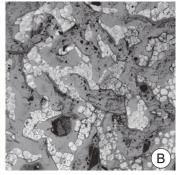




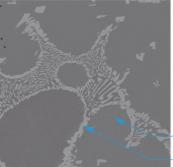
Sample: IC bonds - Au bond on metabolized Si wafer

A BSE 2kV | 20pA | 320 μs/pxl B BSE 5kV | 20pA | 100 μs/pxl





Sample: phases of LU_2O_3 , $Lu_3AI_5O_{12}$ and Zr_2O **A** SE 2kV | 80pA | 100 µs/pxl **B** BSE 3kV | 80pA | 100 µs/pxl



Sample: Fe-Al-Nb alloy BSE 10kV | 8100pA | 100 µs/pxl

FE-25AL-0.25Nb FE-20.8AL-27.1Nb



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